

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S11	206	III-V and pattern\$3 same (width or diameter or length) and overla\$3 and @py<"2002"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/05 19:24
S15 3	730	III-V and pattern\$3 same (width or diameter or length) and overla\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/05 19:25
S15 2	206	III-V and pattern\$3 same (width or diameter or length) and overla\$3 and @py<"2002"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/05 19:25
S15 5	2	"6498048".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/05 19:30
S15 4	116	(III-V or gan or gallium near2 nitride) and pattern\$3 same (width or diameter or length) same dislocat\$6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/05 19:30
S15 7	38	etsuo near2 morita.in. and ("iii-v" or gan)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/05 19:46
S15 6	8	etsuo near2 morita.in. and pitch\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/05 19:46
S14 8	8	etsuo near2 morita.in. and pitch\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/05 19:46
S15 8	2	(iii-v or gallium near2 nitride) near10 pattern\$6 near15 pitch\$5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/05 19:47

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S15 1	1	(iii-v or gallium near2 nitride) near10 pattern\$6 near15 pitch\$5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/05 19:47
S15 9	153	etch\$6 same pattern\$5 same (gan or gallium near2 nitride) same light near2 emit\$6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/05 19:48
S13 4	17	etch\$6 same pattern\$5 same (gan or gallium near2 nitride) same light near2 emit\$6 and @py<"2001"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/05 19:48
S11 0	30	(elo or epitax\$5 near2 lateral near2 overgrow\$5) near15 (gan or gallium near2 nitride) near15 again	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/05 19:48
S16 1	32	pattern\$6 near5 different same overlap\$6 and ("iii-v" or gan or gallium near2 nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/05 19:49
S16 0	9	(elo or epitax\$5 near2 lateral near2 overgrow\$5) near15 (gan or gallium near2 nitride) near15 repeat\$6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/05 19:49
S10 6	25	pattern\$6 near5 different same overlap\$6 and ("iii-v" or gan or gallium near2 nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/05 19:49
S64	76	pattern\$5 near10 pitch\$5 same overlay\$6 and semiconductor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/05 19:49
S16 3	300	pattern\$5 near10 pitch\$5 and (gan or gallium near2 nitride or "iii-v")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/05 19:50
S16 2	8581	pattern\$5 near10 pitch\$5 and semiconductor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/05 19:50

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S16 4	43	pattern\$5 near10 pitch\$5 same (gan or gallium near2 nitride or "iii-v")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/05 19:51
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